NSN 5961-00-528-9858



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-528-9858 **Inclosure Material:** Metal **Overall Length:** 1.218 inches **Overall Diameter:** 0.380 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-111 **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 15.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 12.5 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 82577-928399 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 4 tab, solder lug Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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